

Do Capacitance Measurements Reveal Light-induced Bulk Dielectric Changes in Photovoltaic Perovskites?

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Abstract

Several studies have identified complex interactions between photogenerated carriers and the crystal lattice in perovskite materials for photovoltaics, which are regarded to have an inherently soft character. Light is known to induce phase segregation in mixed halide perovskites, enhances piezoelectricity, and changes dipole moments of the unit cell. Therefore, it is appealing to consider photogenerated variations in the bulk polarizability and dielectric properties. Light-induced bulk polarization changes should be observable by capacitance measurements, preferentially at intermediate frequencies where the geometrical capacitance dominates. However, capacitance spectra are influenced by several capacitive and resistive mechanisms, which are also modulated by light. Capacitances may arise from dielectric bulk polarization, space-charge depletion zones, chemical electronic bulk storage and interfacial accumulation mechanisms. This variety of capacitive mechanisms may induce wrong interpretations and produce misleading outcomes when uncritically connected to the bulk polarization response. It is shown here how capacitance-voltage analyses performed at a given frequency are influenced by overlapping effects that mask the actual value of the geometrical capacitance. Careful analyses are then needed before attributing the light-induced modulation of the measured capacitance to hybrid perovskite dielectric changes.

Introduction

Hybrid perovskites have emerged as outstanding materials to be incorporated into many different optoelectronic and energy technologies, from photovoltaics,¹⁻⁶ light-emitting devices⁷⁻⁸ and wave guides⁹ to ion intercalation electrodes for batteries.¹⁰ Among other useful features, high light absorption, excellent carrier transport, reduced charge recombination¹¹⁻¹² and low-cost processing are fostering academic and technological studies to fully understand its operating mechanisms. The scope of the present work is approaching hybrid $\text{CH}_3\text{NH}_3\text{PbI}_3$ perovskite and related variants, which are currently in the focus of research in the field of photovoltaics.¹³ Other hybrid perovskites where, for instance ferroelectric behavior has been verified,¹⁴ are beyond the objectives of our analysis.

Key properties to be thoroughly examined are dielectric parameters of the material, and specially bulk polarizability variations with composition, structure, and incoming light. It is recognized that hybrid perovskite materials are inherently soft, even in the dark. The organic cation exhibits positional dynamic disorder thus contributing to the increase in polarizability.¹⁵ PbI_6 octahedra that make up the perovskite unit cell structure rotate around the c axis.¹⁶⁻¹⁷ Moreover, cooperative ionic off-centering might contribute to local polarization, eventually giving rise to long range ion displacement and macroscopic polarization.¹⁸ By modulated electro-absorption spectroscopy, a light-induced change in the dipole moment of the unit cell, exceeding that of the ground state, has been detected.¹⁹ It is proposed that this effect is related to different mechanisms as ionic polarization, rotation of molecular dipoles and charge migration.²⁰ Photogenerated hot carriers interact with the inorganic lattice inducing rotational disordering and broadening of iodine-iodine correlation at picoseconds time scale.²¹ It is also observed that mixed halide perovskites undergo reversible phase segregation upon illumination.²² All those are examples of the complex interactions occurring between photocarriers and perovskite lattice that would suggest light-induced changes in the dielectric constant ϵ .

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Dielectric properties can be investigated through capacitance (C) measurements in a given range of frequency (f). Capacitance spectra $C(f)$ obtained by impedance spectroscopy (IS) from perovskite-based solar cells of different configurations usually exhibit the trends shown in Figure 1a, as reported in our previous papers.²⁶⁻²⁹ At intermediate frequencies a plateau is identified that is mainly determined by the

geometrical capacitance (per unit area) $C_g = \epsilon\epsilon_0 / L$, which varies with geometrical factors (layer thickness L), and dielectric properties of the perovskite, being ϵ_0 the vacuum permittivity. For conductive-enough contacting layers, the absorber perovskite bulk mainly originates the experimentally-determined C_g .²⁶⁻²⁹ The low-frequency part of the spectra usually shows an excess capacitance that results light-dependent. It is attributed to the polarization of the interfaces between the perovskite and the contact layers through the response of electronic accumulation zones formed in the vicinity of the contact.³⁰ The accumulation capacitance C_s accounts for the increase in charge density near the interfaces that exceeds by several orders of magnitude that occurring in the bulk.³⁰ It has been observed that the low-frequency capacitance (in the dark) exhibits a thickness-independent trend reinforcing the interfacial origin of its underlying mechanism.^{28, 30} At higher frequencies the effect of the series resistance is viewed as a decrease in the capacitance value. The set of spectra in Figure 1a are commonly observed when perovskite solar cells are probed at varying illumination intensities, with accumulation mechanisms C_s well separated from the dielectric response C_g .³¹

A question naturally rises as the appearance of light-induced influences on the dielectric properties. If bulk polarizability really changes with light, the electrical response could vary accordingly opening as a consequence room for new kind of applications. This is indeed an appealing possibility suggested by several light effects reported for hybrid perovskites such as phase segregations,²² light-enhanced piezoelectricity³² and increased ionic conductivity.³³ But light-induced bulk polarization changes should be observable by capacitance measurements, preferentially at intermediate frequencies where C_g dominates. (This is indeed suggested in a recent work.²⁵) It is discussed here that several mechanisms modulated by light, but not related to any change in the bulk polarizability, are able to introduce distortions in the capacitance spectra. This may induce wrong interpretations and produce misleading outcomes when uncritically connected to the bulk polarization response. Careful analyses are then needed before attributing the light-induced modulation of the capacitance values to material dielectric changes.

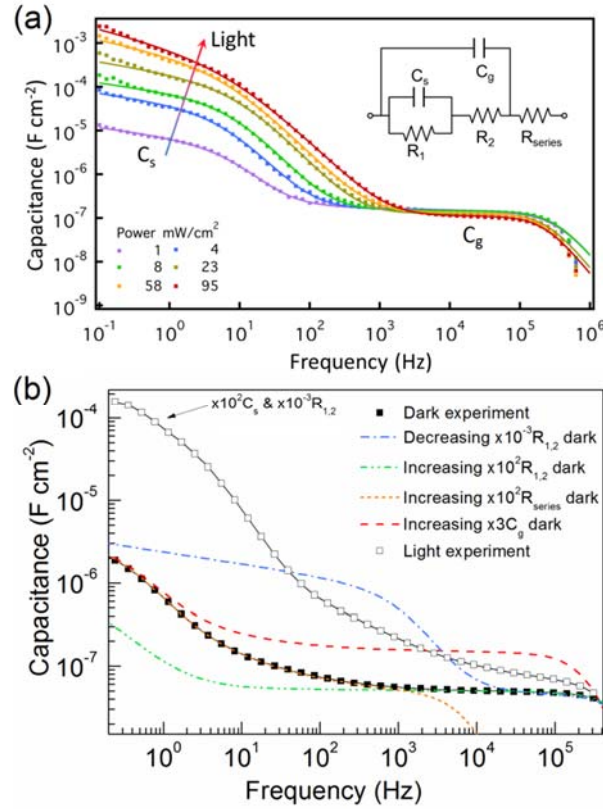


Figure 1. (a) Capacitance spectra measured under short-circuit conditions at varying irradiation intensities corresponding to a device of planar structure FTO/TiO₂/CH₃NH₃PbI₃/spiro-OMeTAD/Au. Solid lines correspond to fits using the equivalent circuit in the inset R_{series} accounts for the series resistance. C_s and C_g are the surface accumulation capacitance and geometrical capacitance, respectively. R_1 and R_2 are related to the recombination current flux. Adapted with permission from ref. ³⁴. Copyright 2016 American Chemical Society. (b) Experimental capacitance spectra at short-circuit conditions (dots) in dark and under 1 sun illumination of a CH₃NH₃PbI₃-based device with TiO₂ mesoporous electron contact matrix and fittings (solid lines) to equivalent circuit inset in (a). Experiment performed at room conditions. Some effects when numerically varying parameters C_s , C_g , R_1 and R_2 are shown with dashed lines, as indicated, to illustrate circuit elements influence on capacitance spectra.

Experimental section

The fabrication of the devices followed the recipes as described in ref. ³⁵. For the IS measurements a PGSTAT-30 potentiostat from Autolab was used and the AC perturbation was of 10 mV. The illumination was supplied by a Sun 2000 system solar simulator from Abet Technologies and the temperatures were controlled with a Quatro Cryosystem from Novocontrol Technologies. The room conditions were of 10-20% humidity and 295-300 K temperature.

Results and discussion

In the following, several modulating effects of the capacitance spectra are introduced, which do not rely in any change of the material bulk polarizability. In practical terms, the geometrical capacitance makes part of a more or less complex equivalent circuit (inset in Figure 1a), which gives rise the entire capacitance spectra $C(f)$. Light may influence resistive parameters as well and modify the capacitance spectra. Also the onset of the C_s contribution is observed in some cases to appear at frequencies as high as 10 kHz, as shown in Figure 1b, which corresponds to capacitance spectra of solar cells comprising TiO₂ mesoporous scaffold. At frequencies in the range of 1-10 kHz in Figure 1b, the numerical modification of circuit elements yield different capacitance values without changing the bulk polarization, i.e. C_g : (i) by reducing the device resistances (dashed blue line), (ii) by increasing the series resistance (dashed green line). Certainly, one expects also capacitance variations by enhancing C_g upon light irradiation increment as simulated (dashed red line). As noted, distortions appear at the intermediate-frequency plateau from a resistive coupling effect. If the response time of low-frequency subcircuit R_1C_s is well-separated, one can estimate the capacitance value at the plateau that equals $C_g R_2 / (R_2 + R_{series})$. If $R_2 \gg R_{series}$ as usually observed for low series resistance devices, the plateau value approaches C_g . However, R_2 decreases at high irradiation intensities as recombination processes are enhanced. Therefore, resistance reduction explains the slight decrease in the intermediate capacitance with light intensity. This is indeed the case observed in Figure 1a at frequencies 1–100 kHz.

One would also expect a contribution introduced by the chemical capacitance C_μ which appears as a consequence of a change in the occupancy of electronic bulk states (density-of-states DOS) caused by a displacement of the carrier Fermi levels that shift upon illumination in the absorber perovskite bulk. However, recent estimations have shown that the relatively small effective conduction (and valence) band DOS³⁶⁻³⁷ entails values for C_μ that lie below C_g and C_s for common light intensities. Hence, this contribution is believed to be masked by other capacitive mechanisms.³⁸

Also significant alterations of the intermediate-frequency capacitance stem from the voltage modulation of the space-charge depletion zone. Doped semiconductors form

Schottky junctions in contact with metals or heterojunctions with other semiconductors. A depletion zone is built in the vicinity of the contact, which gives rise to an excess capacitance $C_{dl} = \varepsilon\varepsilon_0 / w$, being w the width of the depletion zone. Because $w < L$ one expects $C_{dl} > C_g$.³⁷ This type of excess capacitance also acts at intermediate frequencies in those cases in which the perovskite layer contains a sufficiently large density of defects, as illustrated by the constant charge density profile in the inset of Figure 2a. Figure 2a,b are experimental examples of the depletion layer effect in the form of capacitance-voltage $C-V$ and Mott-Schottky $C^{-2}-V$ plots. As observed, only those devices with defect density exceeding $\sim 10^{17} \text{ cm}^{-3}$ are able to yield a distinctive capacitance feature at frequencies in the range of 1–100 kHz. For defect-free or intrinsic perovskite layers the increment cannot be distinguish from the geometrical capacitance background.

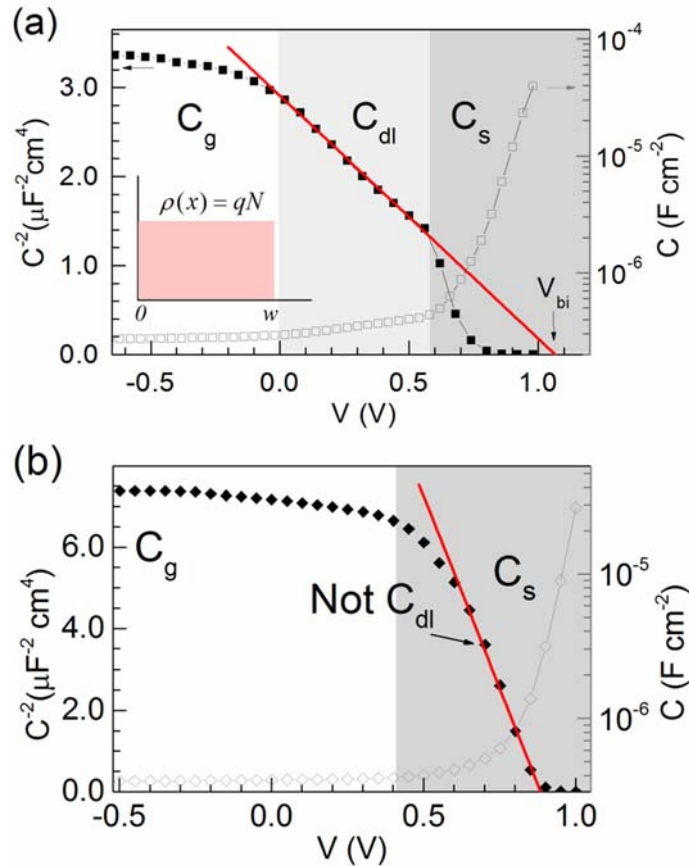


Figure 2. (a, b) Illustrative Mott-Schottky plots of perovskite solar cells (left axis, black filled dotted) and respective capacitance-voltage curves (right axis, gray open dotted). (a) Using $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$, three voltage regions can be distinguished and constant charge density profile can be approached as in the inset. (b) Using $\text{CH}_3\text{NH}_3\text{PbI}_3$ depletion layer capacitance cannot be identified. In both cases, devices comprise a mesoporous TiO_2 matrix in a FTO/ TiO_2 /perovskite/*spiro*-OMeTAD/Au structure. The measurements were carried out in the

dark, at room temperature and the AC perturbation was 10 mV at 10 kHz. Adapted from ref. ²⁷ with permission from American Institute of Physics.

Furthermore, independently of C_{dl} effects, two $C-V$ regimes are highlighted in Figure 2, which dominates at reverse and small forward bias (C_g) and close and/or above the built-in voltage (C_s). Since C_s is sensitive to increments of charge by injection,^{27, 30, 34} it only affects dark capacitance at 1-100 kHz measuring frequency range for large forward bias, overlapping possible bulk carrier storage observation through C_{μ} .^{25, 39} However, under illumination C_s influences the capacitance in the whole DC bias window, producing larger capacitances for higher illumination. This effect is illustrated in Figure 3a for a ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM device, aka inverted cells, which are acknowledged to present a lesser C_s effects than cells comprising oxide contacting layers. This is also traduced in a nearly hysteresis-free behavior in the current density-voltage ($J-V$) curves.^{35, 40-41}

In Figure 3a the capacitance spectra in dark and under 1 sun illumination are presented, and the corresponding $C-V$ curves are displayed (Figure 3b) for 1 kHz and 10 kHz measuring frequencies. It is clear that for larger frequencies lesser capacitances are reported. That capacitance extracted at a given frequency varies with light as a consequence of an overlapping effect caused by the accumulation capacitance C_s , that ultimately produces the measured capacitance value. It is also observable in Figure 1b for regular structures. For inverted samples, the overlapping can be as broader as in Figure 3a, or in a more local frequency range, as shown in Figure S1 (see Supporting Information) where the evolution of capacitance spectra with irradiation intensities is also shown. It is evident that no light-induced change in dielectric properties of the perovskite material can be derived from these measurements.

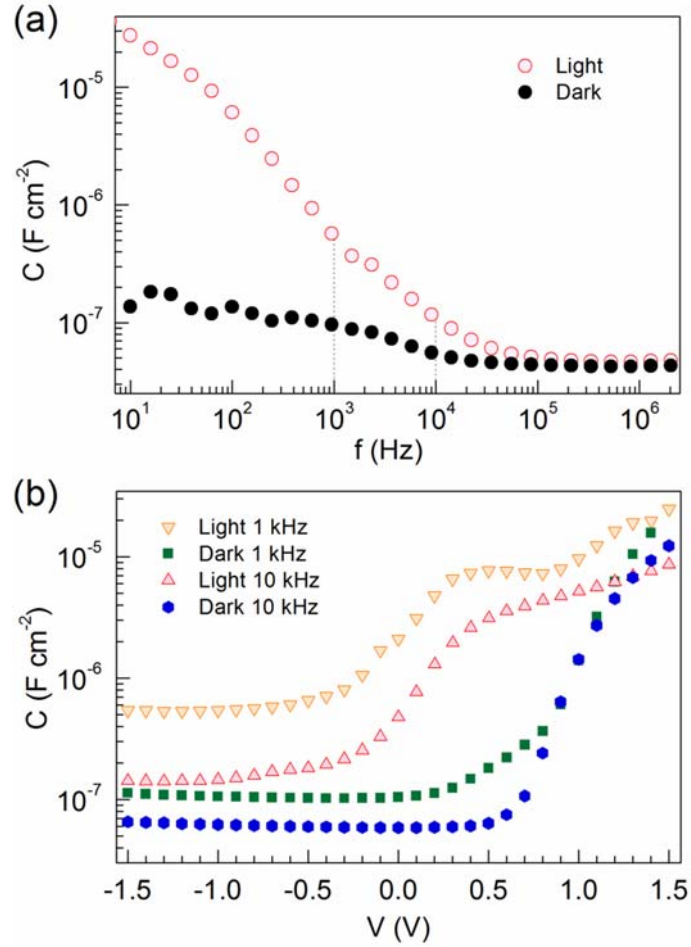


Figure 3. (a) Short-circuit capacitance in dark (filled dots) and under 1 sun illumination (open dots) of a ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM/Ag device and (b) corresponding C - V curves at two frequencies, as indicated. Measurements made at room conditions.

So far we have pointed out the masking effect produced by the overlapping between the accumulation capacitance C_s and the geometrical/chemical value. As clearly visible in Figure 1 and Figure 3, C_s at low-frequencies exceeds C_g by several orders of magnitude. The frequency onset at which accumulation capacitance effect equals the geometrical capacitance may be located at frequencies even larger than 10 kHz, depending on the coupling R_1C_s time constant. It is known that C_s is a prominent effect not only at forward bias but even at reverse bias or short-circuit conditions.³⁴ The capacitance overlapping at intermediate frequencies is particularly important for perovskite solar cells comprising TiO₂ (and other oxides) as electron selective contact but also observable using inverted structures with fullerene contacting layers (Figure 3). Any C - V analysis at a given frequency that directly captures the capacitance value is

influenced then by the C_s overlapping effect identified here. Again, one cannot infer bulk dielectric changes induced by light.

However, minor polarization alterations could be observed as produced by a heating effect under illumination. A thermally-induced change in the dielectric constant is expected to occur, as evidenced in the capacitance-frequency spectra in Figure 4, also for an inverted cell. Once again taking 1 kHz and 10 kHz as example, an exponential increase of capacitance with temperature is experienced that above 300 K may exhibit a temperature coefficient as high as $2 \text{ nF} \cdot \text{cm}^{-2} \cdot \text{K}^{-1}$ when heating the cell. This is an important factor to take into account regarding the time scale of light soaking and temperature control during the measurement of illuminated $C - V$ curves. Furthermore, depending on the perovskite material, even crystal transition phases could be thermally originated due to long term illumination whose impact in the dielectric constant might be important.^{28, 42-43} In addition to this effect at operational temperatures, particularly around 140-180 K several perovskite absorbers present an abrupt gap in the dielectric constant due to transition phases.⁴⁴ This can be also observed in Figure 4, clearest around 10-100 kHz, as previously pointed out in the literature.^{28, 35}

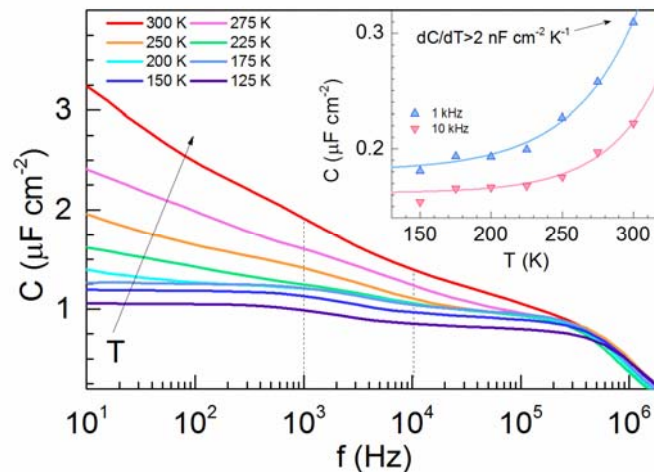


Figure 4. Temperature dependence of dark short-circuit capacitance spectra of a ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM/Ag device. In the inset: capacitance as a function of temperature at two different measuring frequencies. Measurements made in dark vacuum.

Conclusions

A survey on different capacitive processes occurring in hybrid perovskite materials and solar cells has been provided. Capacitances may arise from dielectric bulk polarization, space-charge depletion zones, chemical electronic bulk storage and

interfacial accumulation mechanisms. The analysis is focused on the effect of these capacitors on the capacitance spectra $C(f)$, and how parameter variations influence final spectra. Although several studies suggested that light might induce changes in the dielectric properties and polarizability of the perovskite bulk, it is shown here that the observed enhancement of the capacitance at a given frequency in a capacitance-voltage $C-V$ experiment is easily originated by the overlapping effect of interfacial accumulation capacitances. Therefore, simpler explanations exist and allow discarding light-induced variations of the dielectric properties in the perovskite bulk. When uncritically connected to the bulk response, $C-V$ measurement induces wrong interpretations and produces misleading outcomes. Careful analyses are then needed before attributing the light-induced modulation of the capacitance values to dielectric changes in hybrid perovskites.

Associated Content

Supporting Information

The Supporting Information is available free of charge on the [ACS Publications website](#) at DOI:

Capacitance spectra for varying illumination intensities

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